## Abstract Submitted for the MAR06 Meeting of The American Physical Society

Calculated polarizations and piezoelectric constants of wurtzite **ZnO**, CdO and MgO PRIYA GOPAL, UCSB — The macroscopic polarization in wurtzite crystal structures such as GaN and ZnO has a strong influence on the electrical and optical properties. This property has been exploited in GaN/AlGaN heterostructures, where the difference in the polarizations between layers induces an electric field at the interface forming a high mobility two-dimensional electron gas (2DEG) <sup>1</sup>. Here we calculate the polarization and the piezoelectric properties of the corresponding wurtzite-structure binary oxides ZnO, MgO and CdO. The knowledge of these properties is essential to explore the possibility of creating similar high mobility polarization induced 2DEGs in the ZnO-based material system. However, since wurtzite-structure MgO and CdO are not experimentally accessible, the values can be obtained computationally. We use the recently developed self-interaction corrected pseudopotential (pseudo-SIC) implementation <sup>2</sup> of the density functional theory and the widely used Berry phase method <sup>3</sup> for obtaining the polarization and piezoelectric constants. We find that the polarization gradients between the endpoint compounds in the MgO-ZnO-CdO are larger <sup>4</sup> than in the GaN analogues.

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Date submitted: 05 Jan 2006 Electronic form version 1.4

<sup>&</sup>lt;sup>1</sup>U. K. Mishra, Y. Wu, B.P. Keller, S. Keller and S.P. Denbaars *IEEE Transactions* on Microwave theory and Techniques, **46**, 6 (1998)

<sup>&</sup>lt;sup>2</sup>A. Filippetti and N.A. Spaldin *Phys. Rev. B* **67**, 125109 (2003).

<sup>&</sup>lt;sup>3</sup>R. D. Kingsmith and D. Vanderbilt *Phys. Rev. B* **49**, 5828 (1994).

<sup>&</sup>lt;sup>4</sup>P. Gopal and N.A. Spaldin submitted